

# MiniSKiiP<sup>®</sup> 2 Dual

### Half-Bridge

#### SKiiP 24GB12T7V1

#### Features\*

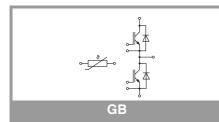
- 1200V Generation 7 IGBTs (T7)
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

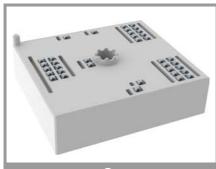
#### Remarks

- Max. case temperature limited to  $T_C=T_S=125$  °C
- Product reliability results valid for Tj≤150 °C (recommended Tion=-40...+150 °C)
- T<sub>j,op</sub>=-40...+150 °C)
  MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information
- For storage and case temperature with TIM see document: "Technical Explanations Thermal Interface Materials"

Absolute	Maximum Ratings	5		<u>.</u>
Symbol	Conditions		Values	Unit
Inverter -	IGBT			•
V <sub>CES</sub>	T <sub>j</sub> = 25 °C		1200	V
Ic	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 70 °C	137	А
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 100 °C	111	А
I <sub>C</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 70 °C	1200 137 111 158 128 128 150 300 -20 20 7 -40 175 109 87 127 101 300 774 -40 175	А
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 100 °C	128	Α
I <sub>Cnom</sub>			150	А
I <sub>CRM</sub>			300	А
V <sub>GES</sub>			-20 20	V
t <sub>psc</sub>	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T <sub>j</sub> = 175 °C	7	μs
Tj		-	-40 175	°C
Inverse -	Diode			
l <sub>F</sub>	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 70 °C	109	А
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 100 °C	87	А
I <sub>F</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 70 °C	127	Α
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 100 °C	101	А
I <sub>FRM</sub>			300	А
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180°	°, T <sub>j</sub> = 150 °C	774	А
Tj			-40 175	°C
Module				•
I <sub>t(RMS)</sub>	T <sub>terminal</sub> = 80 °C, 20	A per spring	200	Α
T <sub>stg</sub>	module without TIN	Λ	-40 125	°C
Visol	AC sinus 50 Hz, t =	1 min	2500	V

Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT					
V <sub>CE(sat)</sub>	I <sub>C</sub> = 150 A	T <sub>j</sub> = 25 °C		1.55	1.70	V
	V <sub>GE</sub> = 15 V	T <sub>j</sub> = 150 °C		1.72	1.96	V
	chiplevel	T <sub>j</sub> = 175 °C		1.75	2.01	V
V <sub>CE0</sub>		T <sub>j</sub> = 25 °C		0.90	1.00	V
	chiplevel	T <sub>j</sub> = 150 °C		0.75	0.83	V
		T <sub>j</sub> = 175 °C		0.72	0.80	V
r <sub>CE</sub>		T <sub>j</sub> = 25 °C		4.3	4.7	mΩ
	V <sub>GE</sub> = 15 V _ chiplevel	T <sub>j</sub> = 150 °C		6.5	7.5	mΩ
		T <sub>j</sub> = 175 °C		6.9	8.1	mΩ
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_{C} = 3.4$	mA	5.15	5.8	6.45	V
I <sub>CES</sub>	$V_{GE} = 0 V, V_{CE} = 12$	200 V, T <sub>j</sub> = 25 °C			1.5	mA
Cies	N/ 05.1/	f = 1 MHz		30.20		nF
C <sub>oes</sub>	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 V	f = 1 MHz		0.39		nF
C <sub>res</sub>		f = 1 MHz		1.08		nF
Q <sub>G</sub>	V <sub>GE</sub> = - 8V + 15 V			2100		nC
R <sub>Gint</sub>	T <sub>j</sub> = 25 °C			1.0		Ω





# MiniSKiiP<sup>®</sup> 2 Dual

### Half-Bridge

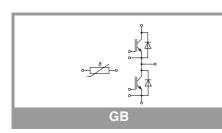
### SKiiP 24GB12T7V1

#### Features\*

- 1200V Generation 7 IGBTs (T7)
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

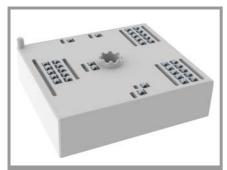
#### Remarks

- Max. case temperature limited to  $T_{C}{=}T_{S}{=}125\ ^{\circ}\text{C}$
- Product reliability results valid for  $T_j \le 150$  °C (recommended  $T_{i,op} = -40...+150$  °C)
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information
- For storage and case temperature with TIM see document: "Technical Explanations Thermal Interface Materials"



Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT					
t <sub>d(on)</sub>		T <sub>j</sub> = 25 °C		173		ns
		T <sub>j</sub> = 150 °C		181		ns
		T <sub>j</sub> = 175 °C		179		ns
t <sub>r</sub>	V <sub>CC</sub> = 600 V I <sub>C</sub> = 150 A	T <sub>j</sub> = 25 °C		32		
		T <sub>j</sub> = 150 °C		37		
		T <sub>j</sub> = 175 °C		39	ns	
Eon	$R_{G \text{ on}} = 1.1 \Omega$	T <sub>j</sub> = 25 °C		6.3		
	1/ .45/451/	T <sub>j</sub> = 150 °C		11		
		T <sub>j</sub> = 175 °C		12		
t <sub>d(off)</sub>		T <sub>j</sub> = 25 °C		347		ns
	@ T <sub>i</sub> = 150 °C:	T <sub>j</sub> = 150 °C		437		ns
	di/dt <sub>on</sub> = 5650 A/µs di/dt <sub>off</sub> = 1530 A/µs dv/dt = 3730 V/µs	T <sub>j</sub> = 175 °C		462 67 103 130		ns
t <sub>f</sub>		T <sub>j</sub> = 25 °C				ns
		T <sub>j</sub> = 150 °C				ns
		T <sub>j</sub> = 175 °C				ns
E <sub>off</sub>		T <sub>j</sub> = 25 °C	10 17			mJ
		T <sub>j</sub> = 150 °C				mJ
		T <sub>j</sub> = 175 °C		18		mJ
R <sub>th(j-s)</sub>	per IGBT, λ <sub>paste</sub> =0.8	3 W/(mK)		0.4		K/W
R <sub>th(j-s)</sub>	per IGBT, λ <sub>paste</sub> =2.5	5 W/(mK)		0.32		K/W

#### Characteristics Symbol Conditions min. max. Unit typ. Inverse - Diode $V_F = V_{EC}$ T<sub>i</sub> = 25 °C 2.17 2.49 ۷ I<sub>F</sub> = 150 A $V_{GE} = 0 V$ T<sub>i</sub> = 150 °C 2.11 2.42 V chiplevel T<sub>i</sub> = 175 °C 2.27 v 1.96 V<sub>F0</sub> T<sub>i</sub> = 25 °C 1.30 1.50 V T<sub>i</sub> = 150 °C chiplevel 0.90 1.10 V T<sub>i</sub> = 175 °C V 0.82 0.98 T<sub>i</sub> = 25 °C 5.8 6.6 mΩ r<sub>F</sub> T<sub>i</sub> = 150 °C 8.1 chiplevel 8.8 mΩ T<sub>i</sub> = 175 °C 7.6 8.6 mΩ T<sub>i</sub> = 25 °C I<sub>RRM</sub> 197 А T<sub>i</sub> = 150 °C 228 А $I_{F} = 150 \text{ A}$ T<sub>i</sub> = 175 °C А 256 $V_{GE} = +15/-15 V$ Qrr T<sub>i</sub> = 25 °C 13 μC $V_{CC} = 600 V$ T<sub>i</sub> = 150 °C 26 μC T<sub>i</sub> = 175 °C 25 μC @ T<sub>i</sub> = 150 °C: $di/dt_{off} = 5550 \text{ A/}\mu \text{s}$ $T_j = 25 \degree \text{C}$ $\mathsf{E}_{\mathsf{rr}}$ 5 mJ T<sub>j</sub> = 150 °C 11 mJ T<sub>i</sub> = 175 °C 12 mJ per Diode, $\lambda_{paste}=0.8 \text{ W/(mK)}$ R<sub>th(j-s)</sub> 0.5 K/W per Diode, $\lambda_{paste} = 2.5 \text{ W/(mK)}$ 0.4 K/W $R_{th(j-s)}$ Module 20 nΗ LCF 2.5 to heat sink 2 Nm $M_s$ w 50 g



# MiniSKiiP<sup>®</sup> 2 Dual

### Half-Bridge

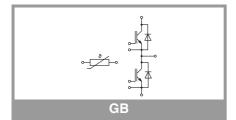
#### SKiiP 24GB12T7V1

#### Features\*

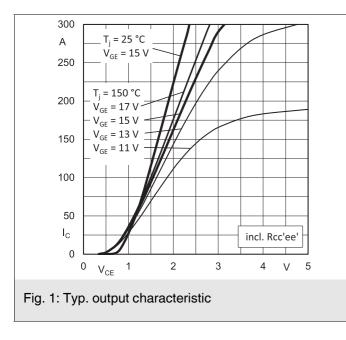
- 1200V Generation 7 IGBTs (T7)
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

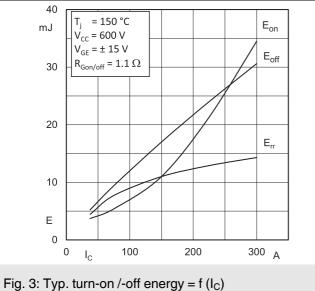
#### Remarks

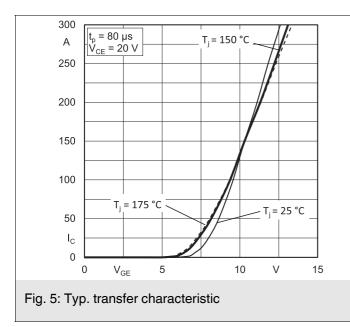
- Max. case temperature limited to  $T_C=T_S=125$  °C
- Product reliability results valid for T<sub>j</sub>≤150 °C (recommended T<sub>ion</sub>=-40...+150 °C)
- T<sub>j,op</sub>=-40...+150 °C)
  MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information
- For storage and case temperature with TIM see document: "Technical Explanations Thermal Interface Materials"

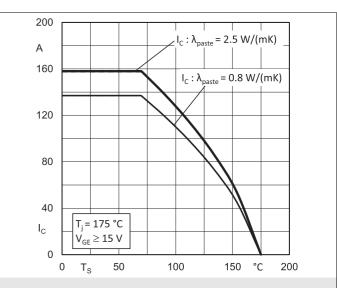


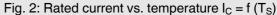
Characteristics							
Symbol	Conditions	min.	typ.	max.	Unit		
Temperate	ure Sensor						
R <sub>100</sub>	T <sub>c</sub> =100°C (R <sub>25</sub> =5 kΩ)	493 ± 5%			Ω		
B <sub>100/125</sub>	R <sub>(T)</sub> =R <sub>100</sub> exp[B <sub>100/125</sub> (1/T-1/T <sub>100</sub> )]; T[K];	3550 ±2%		К			

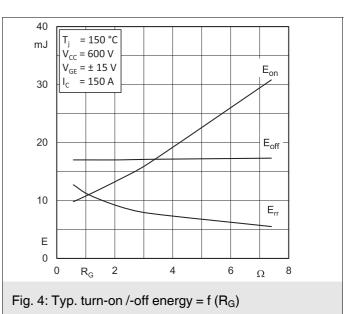


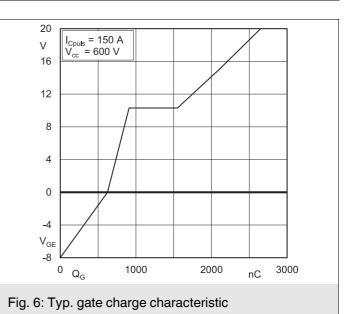


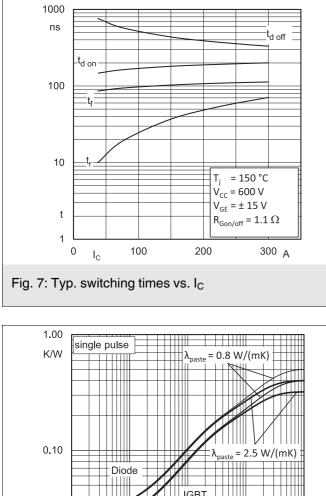


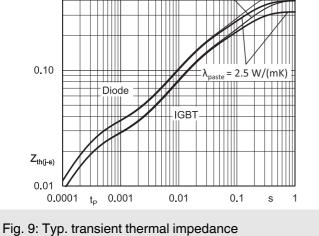


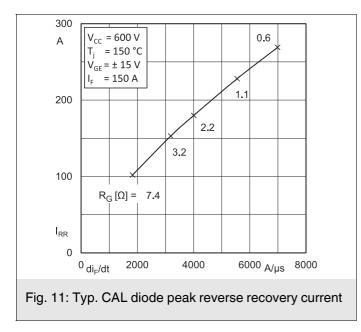












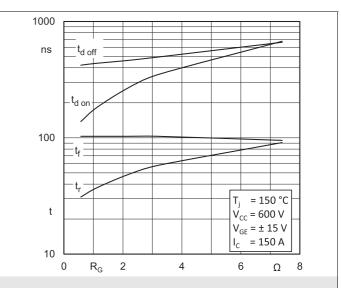
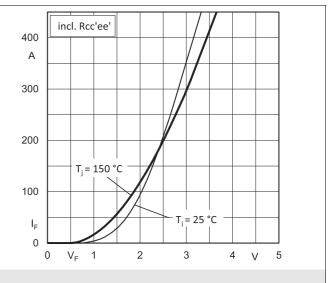
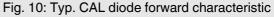
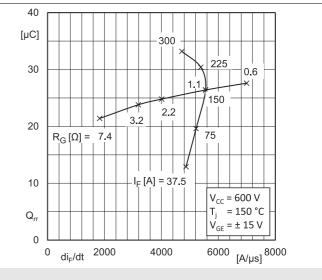
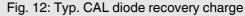


Fig. 8: Typ. switching times vs. gate resistor R<sub>G</sub>



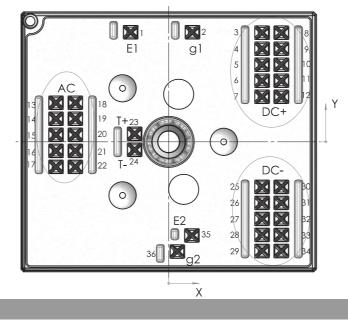




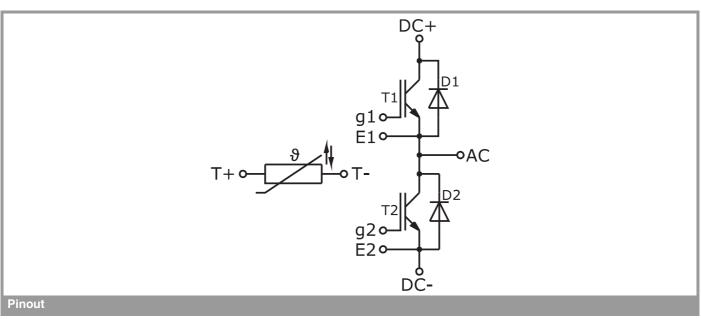


Pin out							
Pin	X	Y	Function	Pin	X	Y	Function
1	-7,58	21,9	E1	19	-18,62	4,6	AC
2	4,72	21,9	g1	20	-18,62	1,4	AC
3	18,62	21,8	DC+	21	-18,62	-1,8	AC
4	18,62	18,6	DC+	22	-18,62	-5	AC
5	18,62	15,4	DC+	23	-6,78	1,6	T+
6	18,62	12,2	DC+	24	-6,78	-1,6	Т-
7	18,62	9	DC+	25	18,62	-9	DC-
8	22,48	21,8	DC+	26	18,62	-12,2	DC-
9	22,48	18,6	DC+	27	18,62	-15,4	DC-
10	22,48	15,4	DC+	28	18,62	-18,6	DC-
11	22,48	12,2	DC+	29	18,62	-21,8	DC-
12	22,48	9	DC+	30	22,48	-9	DC-
13	-22,48	7,8	AC	31	22,48	-12,2	DC-
14	-22,48	4,6	AC	32	22,48	-15,4	DC-
15	-22,48	1,4	AC	33	22,48	-18,6	DC-
16	-22,48	-1,8	AC	34	22,48	-21,8	DC-
17	-22,48	-5	AC	35	4,62	-18,7	E2
18	-18,62	7,8	AC	36	1,72	-21,9	g2

all values in mm



**Pinout and Dimensions** 



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

#### **\*IMPORTANT INFORMATION AND WARNINGS**

The specifications of SEMIKRON products may not be considered as guarantee or assurance of product characteristics ("Beschaffenheitsgarantie"). The specifications of SEMIKRON products describe only the usual characteristics of products to be expected in typical applications, which may still vary depending on the specific application. Therefore, products must be tested for the respective application in advance. Application adjustments may be necessary. The user of SEMIKRON products is responsible for the safety of their applications embedding SEMIKRON products and must take adequate safety measures to prevent the applications from causing a physical injury, fire or other problem if any of SEMIKRON products become faulty. The user is responsible to make sure that the application design is compliant with all applicable laws, regulations, norms and standards. Except as otherwise explicitly approved by SEMIKRON in a written document signed by authorized representatives of SEMIKRON, SEMIKRON products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury. No representation or warranty is given and no liability is assumed with respect to the accuracy, completeness and/or use of any information herein, including without limitation, warranties of non-infringement of intellectual property rights of any third party. SEMIKRON does not assume any liability arising out of the applications or use of any product; neither does it convey any license under its patent rights, copyrights, trade secrets or other intellectual property rights, nor the rights of others. SEMIKRON makes no representation or warranty of non-infringement or alleged non-infringement of intellectual property rights of any third party which may arise from applications. Due to technical requirements our products may contain dangerous substances. For information on the types in question please contact the nearest SEMIKRON sales office. This document supersedes and replaces all information previously supplied and may be superseded by updates. SEMIKRON reserves the right to make changes.